

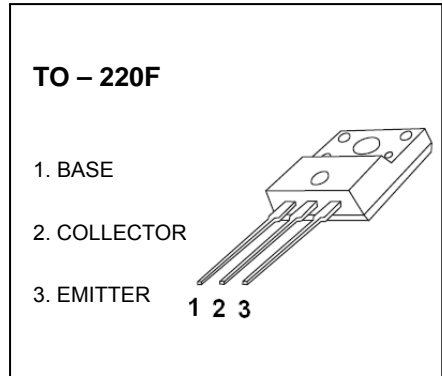


## TO-220F Plastic-Encapsulate Transistors

### 2SA2050 TRANSISTOR (PNP)

#### FEATURES

- High Breakdown Voltage
- General Purpose Switching and Amplification



#### MAXIMUM RATINGS ( $T_a=25^{\circ}\text{C}$ unless otherwise noted)

| Symbol          | Parameter                                   | Value    | Unit                 |
|-----------------|---|----------|----------------------|
| $V_{CBO}$       | Collector-Base Voltage                      | -180     | V                    |
| $V_{CEO}$       | Collector-Emitter Voltage                   | -160     | V                    |
| $V_{EBO}$       | Emitter-Base Voltage                        | -6       | V                    |
| $I_C$           | Collector Current                           | -1.5     | A                    |
| $P_C$           | Collector Power Dissipation                 | 1.5      | W                    |
| $R_{\theta JA}$ | Thermal Resistance From Junction To Ambient | 83       | $^{\circ}\text{C/W}$ |
| $T_j$           | Junction Temperature                        | 150      | $^{\circ}\text{C}$   |
| $T_{stg}$       | Storage Temperature                         | -55~+150 | $^{\circ}\text{C}$   |

#### ELECTRICAL CHARACTERISTICS ( $T_a=25^{\circ}\text{C}$ unless otherwise specified)

| Parameter                            | Symbol        | Test conditions                         | Min  | Typ | Max | Unit          |
|--------------------------------------|---------------|---|------|-----|-----|---------------|
| Collector-base breakdown voltage     | $V_{(BR)CBO}$ | $I_C=-1\text{mA}, I_E=0$                | -180 |     |     | V             |
| Collector-emitter breakdown voltage  | $V_{(BR)CEO}$ | $I_C=-10\text{mA}, I_B=0$               | -160 |     |     | V             |
| Emitter-base breakdown voltage       | $V_{(BR)EBO}$ | $I_E=-100\mu\text{A}, I_C=0$            | -6   |     |     | V             |
| Collector cut-off current            | $I_{CBO}$     | $V_{CB}=-180\text{V}, I_E=0$            |      |     | -10 | $\mu\text{A}$ |
| Emitter cut-off current              | $I_{EBO}$     | $V_{EB}=-6\text{V}, I_C=0$              |      |     | -10 | $\mu\text{A}$ |
| DC current gain                      | $h_{FE(1)}$   | $V_{CE}=-5\text{V}, I_C=-0.2\text{A}$   | 60   |     | 240 |               |
|                                      | $h_{FE(2)}$   | $V_{CE}=-5\text{V}, I_C=-1.5\text{A}$   | 50   |     |     |               |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C=-500\text{mA}, I_B=-50\text{mA}$   |      |     | -1  | V             |
| Transition frequency                 | $f_T$         | $V_{CE}=-10\text{V}, I_C=-0.05\text{A}$ | 50   |     |     | MHz           |

#### CLASSIFICATION OF $h_{FE(1)}$

| RANK  | R      | O       |
|-------|--------|---------|
| RANGE | 60-140 | 100-240 |